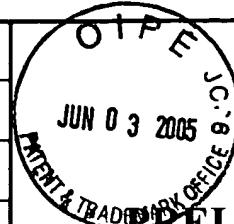


First Named Inventor	Leonard Forbes
Serial No.	10/808,059
Filing Date	March 24, 2004
Group Art Unit	2814
Examiner Name	M. Pizarro Crespo
Confirmation No.	4221
Attorney Docket No.	400.285US01



**PRELIMINARY
AMENDMENT**

Title: NROM MEMORY DEVICE WITH HIGH-PERMITTIVITY GATE DIELECTRIC
FORMED BY THE LOW TEMPERATURE OXIDIZATION OF METALS

Commissioner for Patents
M.S. Amendment
P.O. Box 1450
Alexandria, VA 22313-1450

Prior to initial review, please amend the above-identified application as follows to correct a typographical error in the application filing:

PRELIMINARY AMENDMENT

Serial No. 10/808,059

Title: NROM MEMORY DEVICE WITH HIGH-PERMITTIVITY GATE DIELECTRIC FORMED BY THE
LOW TEMPERATURE OXIDIZATION OF METALS

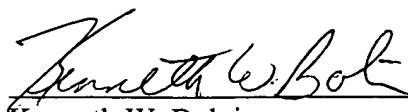
PAGE 3

Attorney Docket No. 400.285US01

If the Examiner has any questions or concerns regarding this application, please contact the undersigned at (612) 312-2211. No new matter has been added and Applicant believes no additional fee is required by this Preliminary Amendment.

Respectfully submitted,

Date: 5/31/05



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